

## Electronic supplementary information

### Efficient and Stable All-Inorganic Perovskite Solar Cells Based on Nonstoichiometric $\text{Cs}_x\text{PbI}_2\text{Br}_x$ ( $x>1$ ) Alloys

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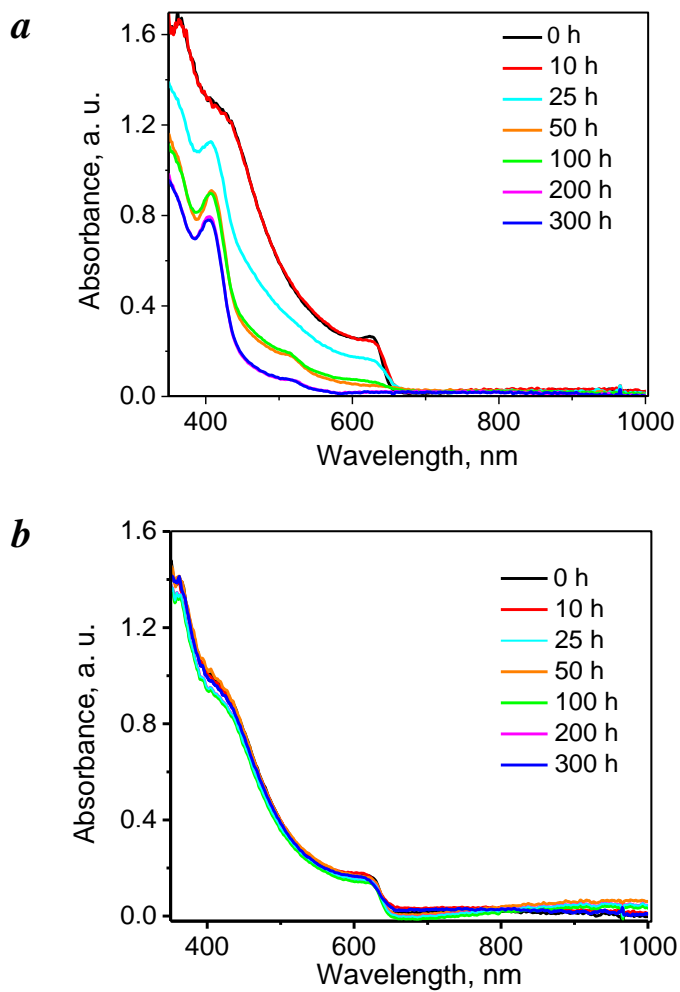
Fig. S1. Evolution of the absorption spectra of the perovskite thin films exposed to white light illumination (metal-halogen lamps,  $100 \text{ mW/cm}^2$ ) at  $70^\circ\text{C}$  in inert atmosphere for the material with the stoichiometric composition  $\text{CsPbI}_2\text{Br}$  (a) and the non-stoichiometric alloy  $\text{Cs}_{1.2}\text{PbI}_2\text{Br}_{1.2}$  (b).

Fig. S2. Best and average open circuit voltage (a), short circuit current density (b), and fill factor (c) of the devices based on the  $\text{Cs}_x\text{PbI}_2\text{Br}_x$  films with different compositions extracted from  $J$ - $V$  measurements (scan rate of  $0.1 \text{ V/s}$  in forward direction).

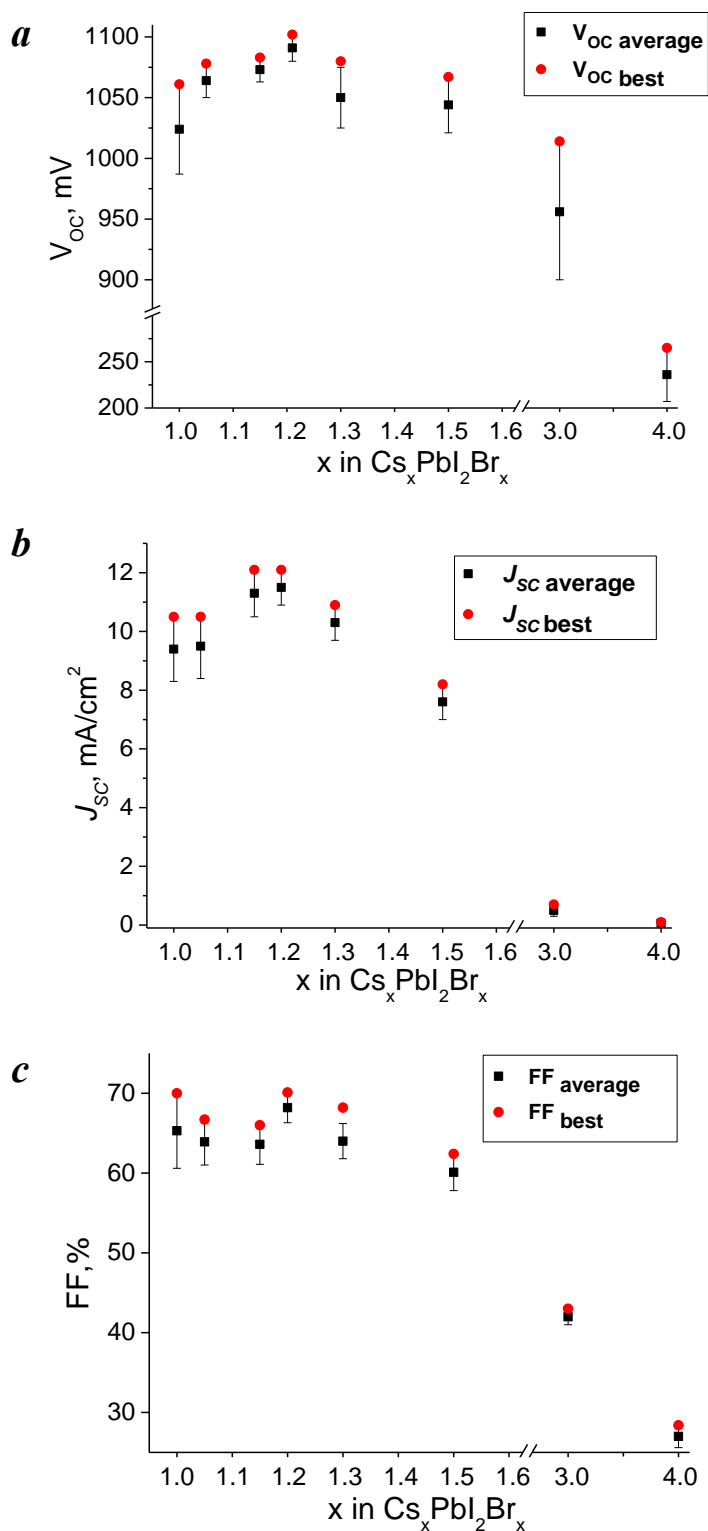
Fig. S3. Steady-state photocurrent measurements under constant load near the device maximal power point at  $V_{\text{max}}$  of  $760 \text{ mV}$ .

Fig. S4. Histograms of the maximum photocurrent distribution from  $I$ - $V$  measurements for the  $\text{CsPbI}_2\text{Br}$  (a) and  $\text{Cs}_{1.2}\text{PbI}_2\text{Br}_{1.2}$  (b) films.

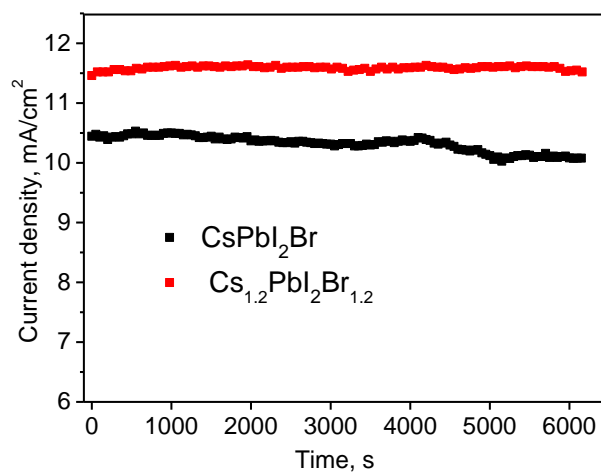
Table S1. Average Cs/Pb atomic ratio in the deposited  $\text{Cs}_x\text{PbI}_2\text{Br}_x$  films according to flame atomic absorption spectrometry.



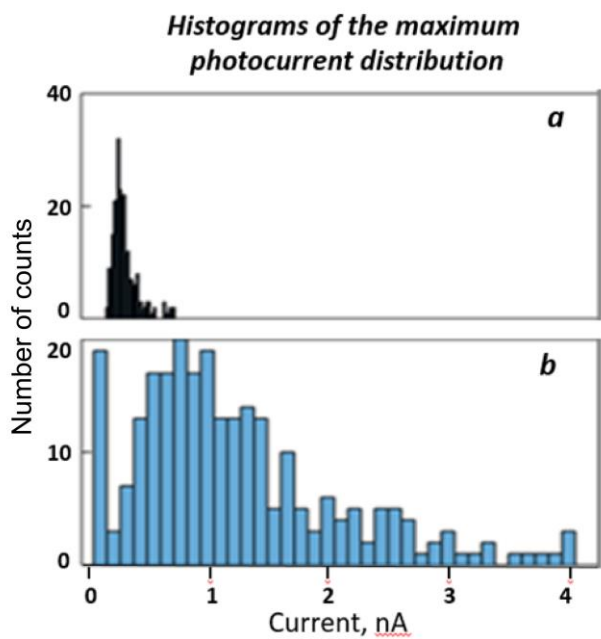
**Figure S1.** Evolution of the absorption spectra of the stoichiometric  $\text{CsPbI}_2\text{Br}$  (a) and non-stoichiometric  $\text{Cs}_{1.2}\text{PbI}_2\text{Br}_{1.2}$  (b) thin films exposed to white light illumination ( $100 \text{ mW/cm}^2$ ) at  $70^\circ \text{C}$  in inert atmosphere ( $\text{O}_2$ ,  $\text{H}_2\text{O} < 0.1 \text{ ppm}$ ).



**Figure S2.** Best and average open circuit voltage (a), short circuit current density (b), and fill factor (c) of the devices based on the  $\text{Cs}_x\text{PbI}_2\text{Br}_x$  films with different compositions extracted from  $J$ - $V$  measurements (scan rate of 0.1 V/s in forward direction).



**Figure S3.** Steady-state photocurrent measurements under constant load near the device maximal power point at  $V_{\text{max}}$  of 760 mV.



**Figure S4.** Histograms of the maximum photocurrent distribution from I-V measurements for the CsPbI<sub>2</sub>Br (a) and Cs<sub>1.2</sub>PbI<sub>2</sub>Br<sub>1.2</sub> (b) films.

**Table S1.** Average Cs/Pb atomic ratio in the deposited  $\text{Cs}_x\text{PbI}_2\text{Br}_x$  films according to flame atomic absorption spectrometry (AAS).

Composition of the films as defined by the thicknesses of CsBr and $\text{PbI}_2$	Cs/Pb atomic ratio experimentally determined using AAS*
$\text{Cs}_{0.95}\text{PbI}_2\text{Br}_{0.95}$	0.95
$\text{CsPbI}_2\text{Br}$	1.02
$\text{Cs}_{1.05}\text{PbI}_2\text{Br}_{1.05}$	1.07
$\text{Cs}_{1.15}\text{PbI}_2\text{Br}_{1.15}$	1.15
$\text{Cs}_{1.2}\text{PbI}_2\text{Br}_{1.2}$	1.18
$\text{Cs}_{1.3}\text{PbI}_2\text{Br}_{1.3}$	1.36
$\text{Cs}_{1.5}\text{PbI}_2\text{Br}_{1.5}$	1.50
$\text{Cs}_{3.0}\text{PbI}_2\text{Br}_{3.0}$	3.02
$\text{Cs}_{4.0}\text{PbI}_2\text{Br}_{4.0}$	3.93

\* - The relative standard deviations of the measurements were within 1%.